

SOD323 Plastic-Encapsulate Diodes

Small Signal Fast Switching Diodes

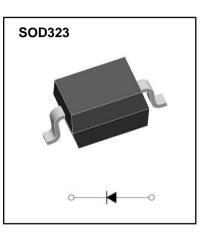
Features

- V_R 75V
- $\bullet I_{FAV}$ 150mA

Applications

• Extreme fast switches

Marking: T4



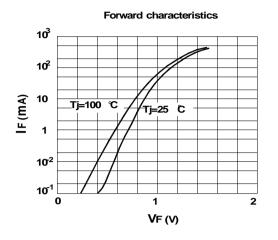
Limiting Values (Absolute Maximum Rating)

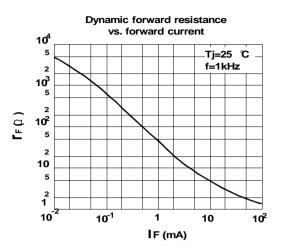
| ltem | Symbol | Unit | Conditions | Limit |
|-------------------------------------|--------|------|------------------|-------------|
| Non-Repetitive Peak Reverse Voltage | VRSM | V | | 100 |
| Repetitive Peak Reverse Voltage | VRRM | V | | 75 |
| Repetitive Peak Forward Current | IFRM | mA | | 300 |
| Non-Repetitive Peak Forward Current | IFSM | А | Pulse width=1 us | 2 |
| Continuous Forward Current | ю | mA | | 150 |
| Power Dissipation | PD | mW | | 200 |
| Junction Temperature | TJ | °C | | 150 |
| Storage Temperature | TSTG | °C | | -55 to +150 |

Electrical Characteristics (T_A=25 $^\circ\!\!\!{}^\circ\!\!\!{}^\circ$ unless otherwise noted)

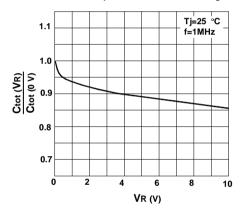
| ltem | Symbol | Unit | Conditions | Min | Max | |
|-------------------------|--------|------|--|-----|-------------------------------|--|
| Forward Voltage | VF | v | IF=1.0mA IF=10mA IF=50mA IF=150mA | | 0.715 0.855 1.0 1.25 | |
| | IR1 | nA | VR=20V | | 25 | |
| Reverse Leakage Current | IR2 | uA | VR=75V | | 1 | |
| Capacitance | СТ | pF | VR=0V,f=1MHz | | 2 | |
| Reverse Recovery Time | trr | ns | IF=IR=10mA,Irr=0.1*IR, RL=100Ω | | 4.0 | |

Typical Characteristics

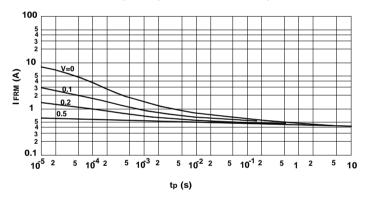


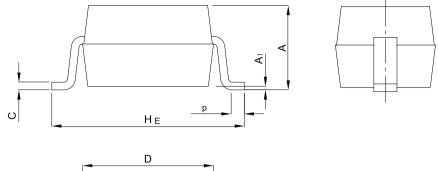


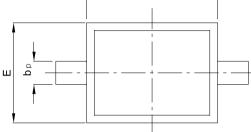
Reverse capacitance vs. reverse voltage



Amissible repetitive peak forward current vs. pulse duration

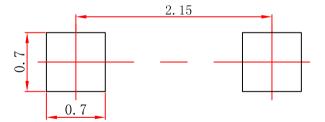






| UNIT | А | bp | С | D | Е | ΗE | A 1 | Lp |
|------|------|------|------|------|------|------|------------|------|
| mm | 1.20 | 0.40 | 0.15 | 1.80 | 1.35 | 2.80 | 0.10 | 0.50 |
| | 0.80 | 0.25 | 0.10 | 1.60 | 1.15 | 2.30 | 0.01 | 0.20 |

SOD323 Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.

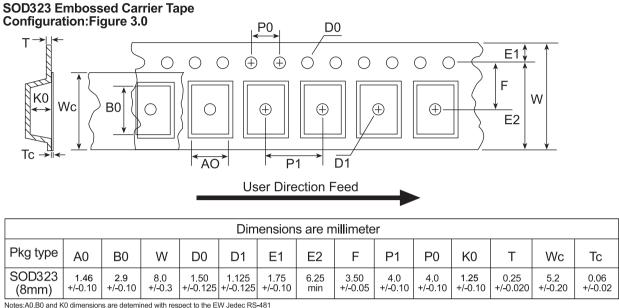
3. The pad layout is for reference purposes only.

NOTICE

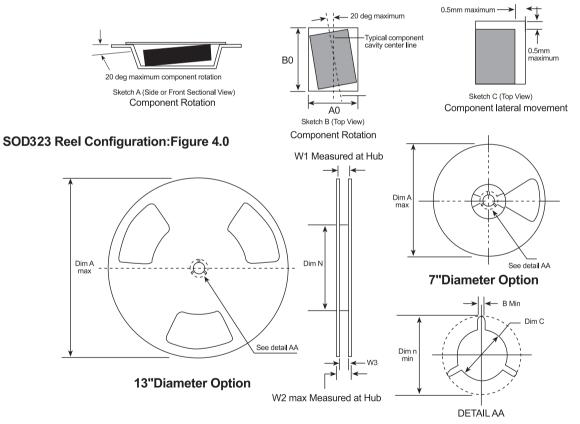
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High Diode Semiconductor

Reel Taping Specifications For Surface Mount Devices-SOD323



Notes:A0,B0 and K0 dimensions are detemined with respect to the EW Jedec RS-481 rotational and lateral movement requirements (see sketches A,B and C).



| Dimensions are in inches and millimeter | | | | | | | | | |
|---|-------------|---------------|--------------|---------------------------------|---------------|-------------|---------------------------------|---------------|-------------------------|
| Type Size | Reel Option | Dim A | Dim B | Dim C | Dim D | Dim N | Dim W1 | Dim W2 | Dim W3 (LSL-USL) |
| 8mm | 7" Dia | 7.00 177.8 | 0.059 1.5 | 512+0.020/-0.008 13+0.5/-0.2 | 0.795 20.0 | 2.165 55 | 0.331+0.059/-0.000 8.4+1.5/0 | 0.567 14.4 | 0.311-0.429 7.9-10.9 |
| 8mm | 13" Dia | 13.00 330 | 0.059 1.5 | 512+0.020/-0.008 13+0.5/-0.2 | 0.795 20.0 | 4.00 100 | 0.331+0.059/-0.000 8.4+1.5/0 | 0.567 14.4 | 0.311-0.429 7.9-10.9 |

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